Computing fundamental domains of crystallographic groups With connections to topological interlocking

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Crystallographic groups

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Let E(n) be the set of all isometries of a dimension $n \in \mathbb{N}$. Then E(n) is a group with the composition of homomorphisms as the group operation.

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$$E(n) \cong O(n) \ltimes \mathbb{R}^n$$
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We denote with φ_o the orthogonal part of φ and with φ_t the vector/translation part of φ .

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$$\mathbb{R}^n \times (O(n) \ltimes \mathbb{R}^n) \to \mathbb{R}^n : (v, (\varphi_o, \varphi_t)) \mapsto v^{(\varphi_o, \varphi_t)} = v^{\varphi_o} + \varphi_t.$$

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- (i) $\bigcup_{\gamma \in \Gamma} F^{\langle \gamma \rangle} = \mathbb{R}^n$,
- (ii) there is a system of representatives $V \subseteq \mathbb{R}^n$ w.r.t. the partition given by the orbits of Γ acting on \mathbb{R}^n such that

$$F^{\circ} \subseteq V \subseteq F$$
.

Example

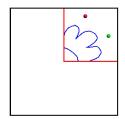
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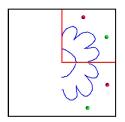
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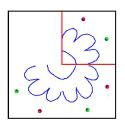
$$p4 := \left\langle \rho := \left(\begin{pmatrix} 0 & 1 \\ -1 & 0 \end{pmatrix}, \begin{pmatrix} 0 \\ 0 \end{pmatrix}^T \right),$$

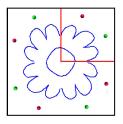
$$\tau_1 := \left(\begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}, \begin{pmatrix} 1 \\ 0 \end{pmatrix}^T \right),$$

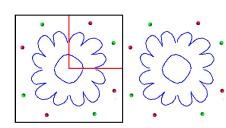
$$\tau_2 := \left(\begin{pmatrix} 1 & 0 \\ 0 & 1 \end{pmatrix}, \begin{pmatrix} 0 \\ 1 \end{pmatrix}^T \right) \right\rangle$$

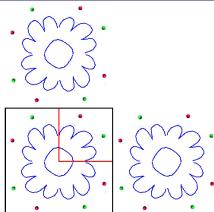


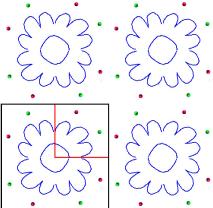


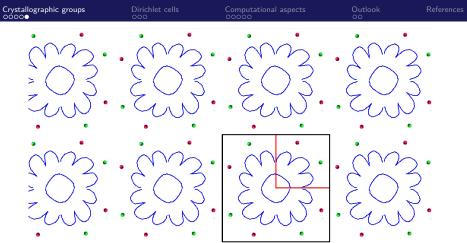


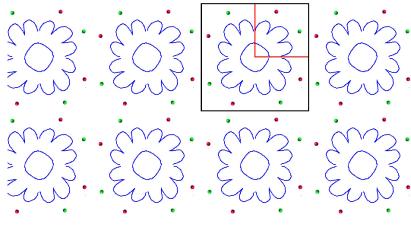












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Definition ([3, Def. III.1])

Let $O \subseteq \mathbb{R}^n$ be a discrete set and $u \in O$ be a point. We call

$$D(u, O) = \bigcap_{w \in O, w \neq u} H^+(u, w).$$

the Dirichlet cell of u.

Crystallograp	hic groups	Dirichlet cells ○●○	Computational aspects	Outlook 00	Reference
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	•		•	•	
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Theorem ([2, Thm. III.11 (ii)])

Let $\Gamma \leq E(n)$ be a crystallographic group and $u \in \mathbb{R}^n$ a point in general position.

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Theorem ([2, Thm. III.11 (ii)])

Let $\Gamma \leq E(n)$ be a crystallographic group and $u \in \mathbb{R}^n$ a point in general position. Then the Dirichlet cell $D(u, u^{\Gamma})$ is a fundamental domain for Γ .

Definition ([1, §3, Thm. 7, with remark after])

Let $B \subset \mathbb{R}^n$ be a closed subset. We define the *volume* of B as the Lebesgue measure of B, so $vol(B) := \lambda(B)$ in the notation of [1].

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It can be shown that all fundamental domains of crystallographic groups have the same volume.

Remark

For every crystallographic group Γ there is a certain subgroup called the translation subgroup that is denoted by

$$\mathcal{T}(\Gamma) \leq \Gamma$$
.

Theorem

Let $\Gamma \leq E(n)$ be a crystallographic group with fundamental domain F and $u \in \mathbb{R}^n$ a point in general position. Then we choose a generating set for Γ and I, K finite index sets, such that

$$\Gamma = \langle \rho_i, \tau_k \mid i \in I, k \in K \rangle,$$

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with $\tau_k \in \mathcal{T}(\Gamma)$ for all $k \in K$ and $\{(\tau_k)_t \mid k \in K\}$ are a basis for the lattice induced by $\mathcal{T}(\Gamma)$. Furthermore, let $\rho_i \in \Gamma$ for $i \in I$ be chosen such that

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Then there is an $A \in \mathbb{N}$ such that the Dirichlet cell $D(u, u^{\Gamma})$ is the intersection of halfspaces $H^+(u, w)$ for words w of length at most A + 1.

Data: a crystallographic group

 $\Gamma = \langle \rho_i, \tau_k \mid i \in I, k \in K \rangle \leq E(n)$ such that

 $\Gamma = \bigcup_{i \in I} \rho_i \mathcal{T}(\Gamma)$, a point u in general position w.r.t. Γ

and the maximal *length* of words in *gens* to check

Result: *triangularComplex*, a triangular complex that is a fundamental domain.

 $\textit{wordsOfLenghtL} \leftarrow \textit{all words in the generators } \textit{gens} \textit{ of length at most } \textit{length}$

for γ in wordsOfLenghtL **do**

Add(elementsInOrbit, u^{γ});

end

halfspaces \leftarrow halfspaces $H_{u,v}$ for all $v \in elementsInOrbit$; fundDom \leftarrow triangular complex given by intersection of halfspaces;

return fundDom;

Time for some examples

Example

Current state Previously presented algorithm is already implemented as part of my masters thesis.

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Next steps

Implement above in SimplicialSurfaces Package

Improve algorithm by automatically running until expected volume is reached

Check if h-vector conversion can be done more efficiently

Consider numerical effects

Why work on this?

Goal is to deform fundamental domains in such a way, that they continue to be fundamental domains but also fulfill the *topological interlocking property*.

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Definition

A block $B \subseteq \mathbb{R}^3$ is called topologically interlocking, if there is an assembly of it, such that by fixing a subset of the assembly there is no subset of the remaining blocks that can be moved without intersecting any blocks.

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